EFC4627R



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N-Channel Power MOSFET 12V, 6A, 29.5mΩ, Dual EFCP

Features

- 2.5V drive
- Protection diode in

- Common-drain type
- Halogen free compliance

Applications

• Lithium-ion battery charging and discharging switch

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V _{SSS}		12	V
Gate to Source Voltage	V _{GSS}		±10	٧
Source Current (DC)	IS		6	Α
Source Current (Pulse)	I _{SP}	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.4	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	84	°C /W
When mounted on ceramic substrate (5000mm ² ×0.8mm)			

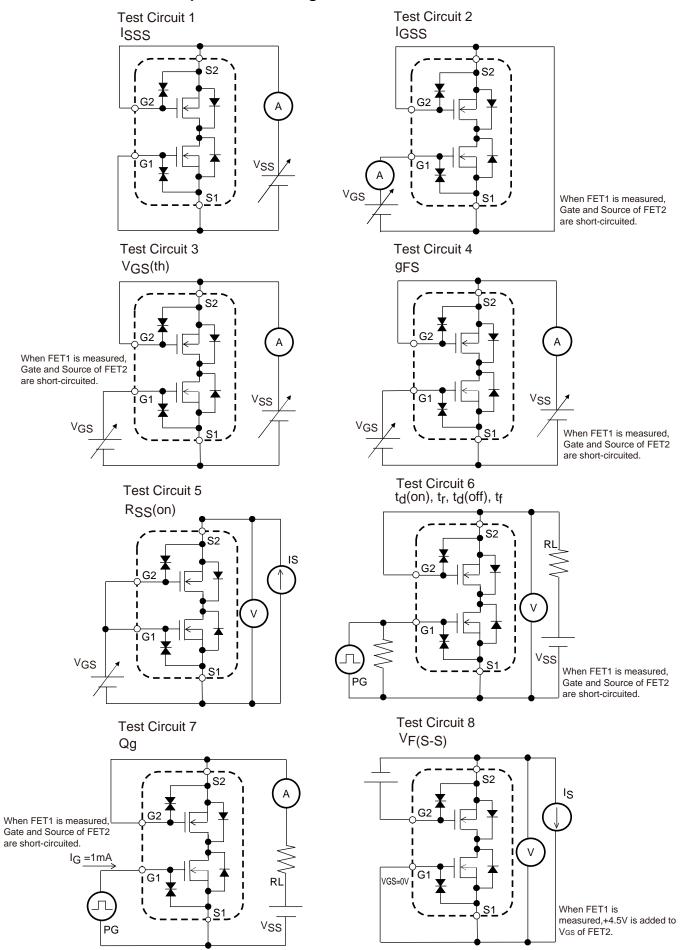
Electrical Characteristics at Ta = 25°C

Parameter	Cumbal	Conditions		Value		Unit	
Parameter	Symbol			min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	IS=1mA, VGS=0V	Test Circuit 1	12			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =10V, V _{GS} =0V	Test Circuit 1			1	μΑ
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{SS} =6V, I _S =1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	9FS	V _{SS} =6V, I _S =2A	Test Circuit 4		4.8		S
	RSS(on)1	I _S =2A, V _{GS} =4.5V	Test Circuit 5	18.5	23.9	29.5	mΩ
	RSS(on)2	I _S =2A, V _{GS} =4.0V	Test Circuit 5	19.7	25.4	31.3	mΩ
Static Source to Source On-State Resistance	RSS(on)3	I _S =2A, V _{GS} =3.8V	Test Circuit 5	20.3	26.1	32.3	mΩ
Resistance	Rss(on)4	I _S =2A, V _{GS} =3.1V	Test Circuit 5	23.5	30.3	39.0	mΩ
	Rss(on)5	I _S =2A, V _{GS} =2.5V	Test Circuit 5	29.3	37.7	50.5	mΩ
Turn-ON Delay Time	t _d (on)				75		ns
Rise Time	t _r	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	T O' ' . O		740		ns
Turn-OFF Delay Time	t _d (off)	VSS=6V, VGS=4.5V, IS=2A Test Circuit 6			2340		ns
Fall Time	tf				2320		ns
Total Gate Charge	Qg	V _{SS} =6V, V _{GS} =4.5V, I _S =6A	Test Circuit 7		13.4		nC
Forward Source to Source Voltage	VF(S-S)	I _S =3A, V _G S=0V	Test Circuit 8		0.76		V

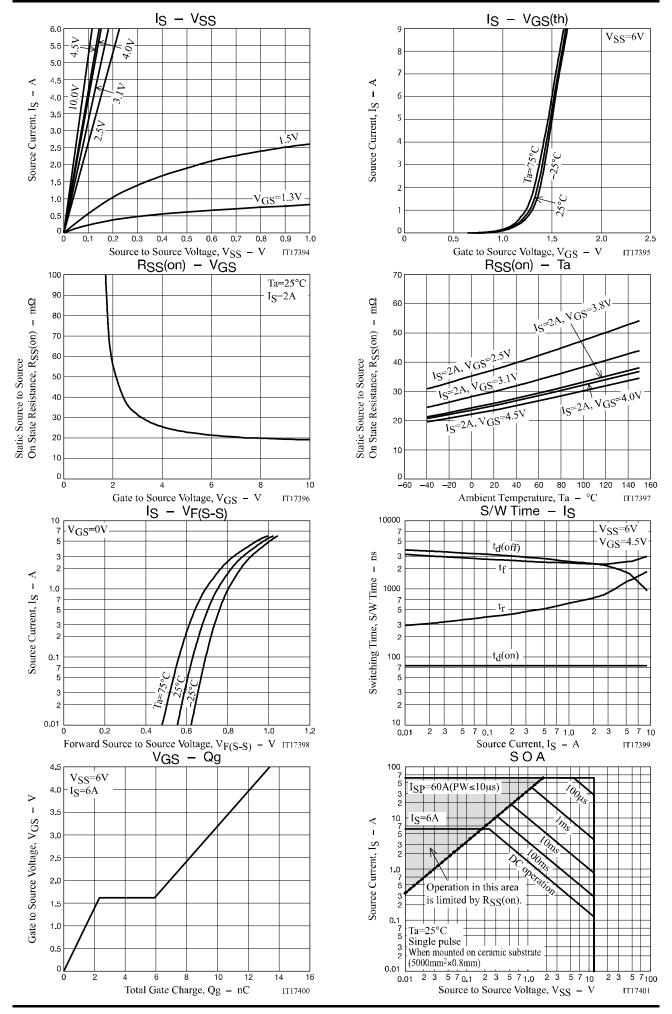
ORDERING INFORMATION

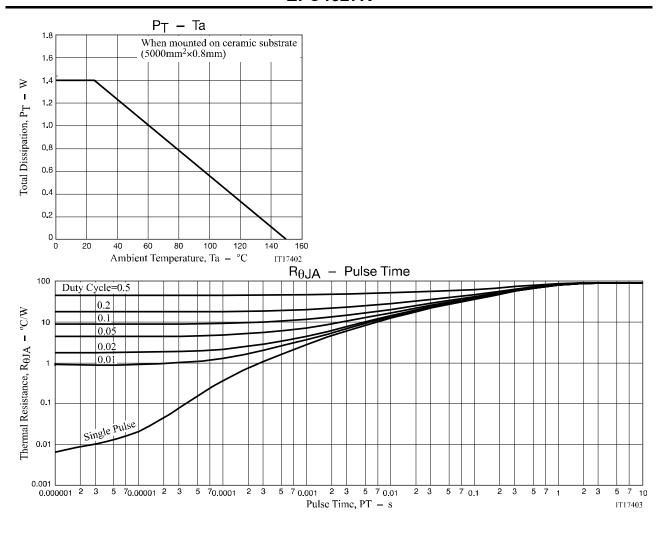
See detailed ordering and shipping information on page 5 of this data sheet.

Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.





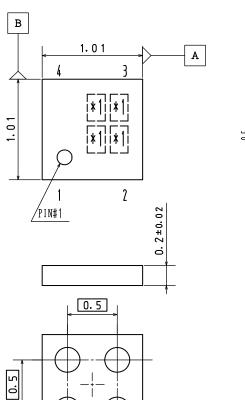
Package Dimensions

EFC4627R-TR

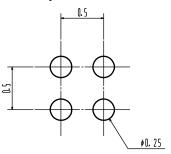
EFCP1010-4DG-020

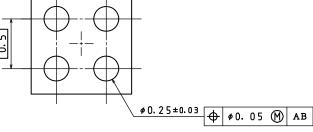
Unit: mm

- 1: Source1
- 2: Gate1
- 3: Gate2
- 4: Source2



Recommended Soldering Footprint

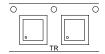




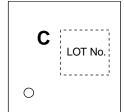
Ordering & Package Information

Device	Package	Shipping	note
EFC4627R-TR	EFCP	8,000 pcs. / reel	Pb-Free and Halogen Free

Packing Type: TR

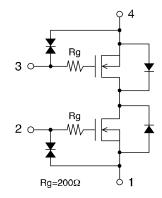


Marking



Electrical Connection

*1:Lot indication



Note on usage : Since the EFC4627R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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